Initial Review

BOX AF

Docket No. 0756-935

1/1/96 VSpaus

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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j (AVIL 40	In re	PATENT application of:)	
	JUN 25	Shung	ei YAMAZAKI et al.)	Ex. Wilczewski
3	1996	,	No. 08/160,909)	Art Unit No. 1107
10	RADEMAR	Filed:	December 3, 1993)	
		For:	METHOD OF FABRICATING)	
			SEMICONDUCTOR DEVICES AND)	
			APPARATUS FOR PROCESSING)	
			A SEMICONDUCTOR)	

PETITION TO ACCEPT INFORMATION DISCLOSURE STATEMENT AFTER FINAL REJECTION

RECEIVED

Honorable Assistant Commissioner for Patents Washington, D.C. 20231

GROUP 1100

JUL - 3 1996

Sir:

The Information disclosure Statement transmitted herewith is being filed after a final action under §1.113, but before the payment of the issue fee.

No item of information in the attached Information Disclosure Statement was cited in a communication from a patent office outside the U.S. in a counterpart foreign application, or to the knowledge of the person whose signature appears below after making reasonable inquiry, was known more than three months prior to the filing date_{SI}of₆ said, Information Disclosure Statement to any individual having 1 122 duty to 130 close such information to the U.S. Patent and Trademark Office.

Applicant hereby petitions for the consideration of the accompanying Information Disclosure Statement in accordance with 37 CFR 1.97(d)(ii).

Applicant submits herewith the petition fee of \$130 as set forth in §1.17(i).

Respectfully submitted,

Costellia Reg. No. 35,483

Sixbey, Friedman, Leedom & Ferguson, P.C.

2010 Corporate Ridge, Suite 600

McLean, Virginia 22102

(703) 790-9110